


**SURFACE MOUNTABLE  
PHASE CONTROL SCR**

**Description/Features**

The 16TTS..S **SAFEIR** series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125° C junction temperature.

Typical applications are in input rectification (soft start) and these products are designed to be used with International Rectifier input diodes, switches and output rectifiers which are available in identical package outlines.

	$V_T < 1.4V @ 10A$
	$I_{TSM} = 200A$
	$V_{RRM} = 800 \text{ to } 1600V$

**Output Current in Typical Applications**

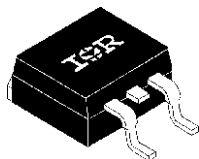
Applications	Single-phase Bridge	Three-phase Bridge	Units
NEMA FR-4 or G10 glass fabric-based epoxy with 4 oz (140µm) copper	2.5	3.5	A
Aluminum IMS, $R_{thCA} = 15^\circ C/W$	6.3	9.5	
Aluminum IMS with heatsink, $R_{thCA} = 5^\circ C/W$	14.0	18.5	

$T_A = 55^\circ C, T_J = 125^\circ C, \text{footprint } 300\text{mm}^2$

**Major Ratings and Characteristics**

Characteristics	16TTS..S	Units
$I_{T(AV)}$ Sinusoidal waveform	10	A
$I_{RMS}$	16	A
$V_{RRM}/V_{DRM}$	up to 1600	V
$I_{TSM}$	200	A
$V_T @ 10 A, T_J = 25^\circ C$	1.4	V
dv/dt	500	V/µs
di/dt	150	A/µs
$T_J$	-40 to 125	°C

**Package Outline**



**D² PAK (SMD-220)**

Voltage Ratings

Part Number	$V_{RRM}$ , maximum peak reverse voltage V	$V_{DRM}$ , maximum peak direct voltage V	$I_{RRM}/I_{DRM}$ 125°C mA
16TTS08S	800	800	10
16TTS12S	1200	1200	
16TTS16S	1600	1600	

Absolute Maximum Ratings

Parameters	16TTS..S	Units	Conditions
$I_{T(AV)}$ Max. Average On-state Current	10	A	@ $T_C = 98^\circ\text{C}$ , 180° conduction half sine wave
$I_{RMS}$ Max. RMS On-state Current	16		
$I_{TSM}$ Max. Peak One Cycle Non-Repetitive Surge Current	170 200		10ms Sine pulse, rated $V_{RRM}$ applied 10ms Sine pulse, no voltage reapplied
$I^2t$ Max. $I^2t$ for fusing	144 200	$A^2s$	10ms Sine pulse, rated $V_{RRM}$ applied 10ms Sine pulse, no voltage reapplied
$I^2\sqrt{t}$ Max. $I^2\sqrt{t}$ for fusing	2000		$A^2\sqrt{s}$
$V_{TM}$ Max. On-state Voltage Drop	1.4	V	@ 10A, $T_J = 25^\circ\text{C}$
$r_t$ On-state slope resistance	24.0	mΩ	$T_J = 125^\circ\text{C}$
$V_{T(TO)}$ Threshold Voltage	1.1	V	
$I_{RM}/I_{DM}$ Max. Reverse and Direct Leakage Current	0.5 10	mA	$T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$ $V_R = \text{rated } V_{RRM}/V_{DRM}$
$I_H$ Holding Current	Typ. Max. -- 100 100 150		mA
$I_L$ Max. Latching Current	200	Anode Supply = 6V, Resistive load	
dv/dt Max. Rate of Rise of off-state Voltage	500	V/μs	
di/dt Max. Rate of Rise of turned-on Current	150	A/μs	

### Triggering

Parameters	16TTS..S	Units	Conditions
$P_{GM}$ Max. peak Gate Power	8.0	W	
$P_{G(AV)}$ Max. average Gate Power	2.0		
+ $I_{GM}$ Max. peak positive Gate Current	1.5	A	
- $V_{GM}$ Max. peak negative Gate Voltage	10	V	
$I_{GT}$ Max. required DC Gate Current to trigger	90	mA	Anode supply = 6V, resistive load, $T_J = -10^\circ\text{C}$
	60		Anode supply = 6V, resistive load, $T_J = 25^\circ\text{C}$
	35		Anode supply = 6V, resistive load, $T_J = 125^\circ\text{C}$
$V_{GT}$ Max. required DC Gate Voltage to trigger	3.0	V	Anode supply = 6V, resistive load, $T_J = -10^\circ\text{C}$
	2.0		Anode supply = 6V, resistive load, $T_J = 25^\circ\text{C}$
	1.0		Anode supply = 6V, resistive load, $T_J = 125^\circ\text{C}$
$V_{GD}$ Max. DC Gate Voltage not to trigger	0.25		$T_J = 125^\circ\text{C}$ , $V_{DRM} = \text{rated value}$
$I_{GD}$ Max. DC Gate Current not to trigger	2.0	mA	$T_J = 125^\circ\text{C}$ , $V_{DRM} = \text{rated value}$

### Switching

Parameters	16TTS..S	Units	Conditions
$t_{gt}$ Typical turn-on time	0.9	$\mu\text{s}$	$T_J = 25^\circ\text{C}$
$t_{rr}$ Typical reverse recovery time	4		$T_J = 125^\circ\text{C}$
$t_q$ Typical turn-off time	110		

### Thermal-Mechanical Specifications

Parameters	16TTS..S	Units	Conditions
$T_J$ Max. Junction Temperature Range	-40 to 125	$^\circ\text{C}$	
$T_{stg}$ Max. Storage Temperature Range	-40 to 125	$^\circ\text{C}$	
	Soldering Temperature	240	$^\circ\text{C}$ for 10 seconds (1.6mm from case)
$R_{thJC}$ Max. Thermal Resistance Junction to Case	1.3	$^\circ\text{C}/\text{W}$	DC operation
$R_{thJA}$ Typ. Thermal Resistance Junction to Ambient (PCB Mount)**	40	$^\circ\text{C}/\text{W}$	
wt Approximate Weight	2 (0.07)	g(oz.)	
T Case Style	D <sup>2</sup> Pak (SMD-220)		

\*\*When mounted on 1" square (650mm<sup>2</sup>) PCB of FR-4 or G-10 material 4 oz (140 $\mu\text{m}$ ) copper 40 $^\circ\text{C}/\text{W}$   
 For recommended footprint and soldering techniques refer to application note #AN-994

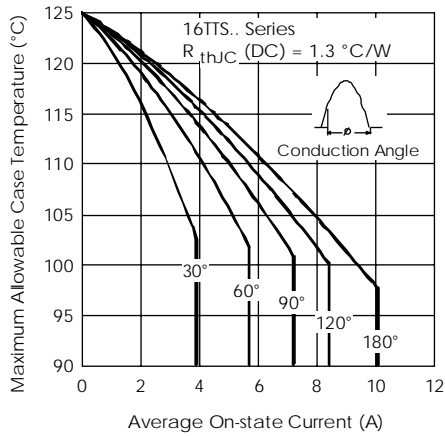


Fig. 1 - Current Rating Characteristics

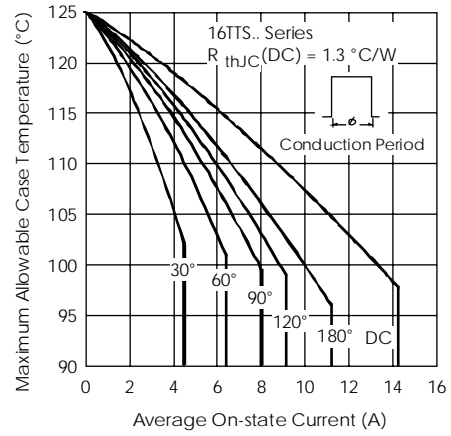


Fig. 2 - Current Rating Characteristics

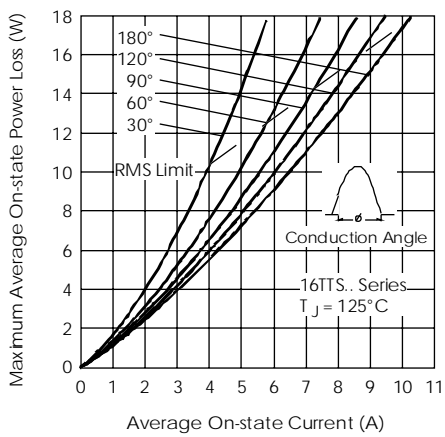


Fig. 3 - On-state Power Loss Characteristics

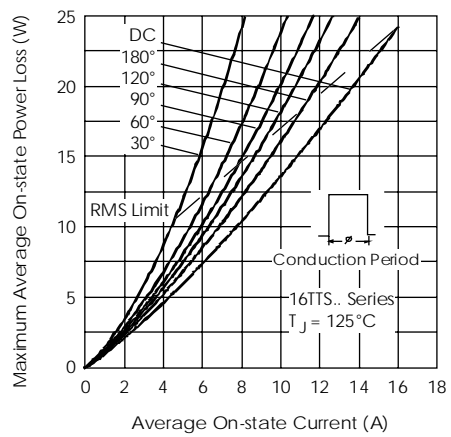


Fig. 4 - On-state Power Loss Characteristics

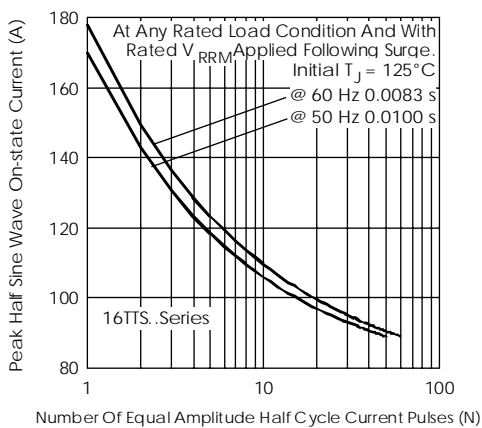


Fig. 6 - Maximum Non-Repetitive Surge Current

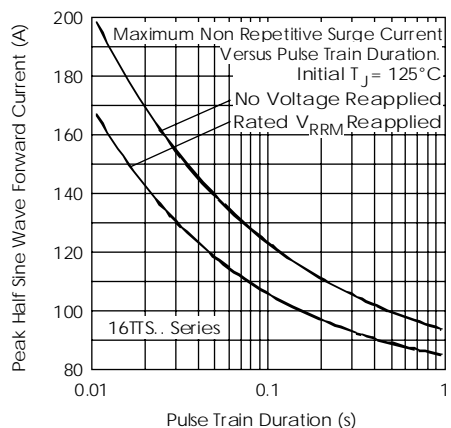


Fig. 7 - Maximum Non-Repetitive Surge Current

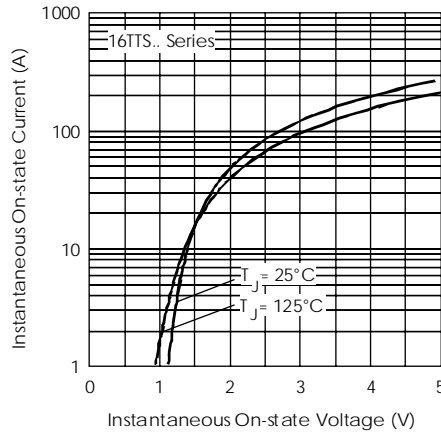


Fig. 7 - On-state Voltage Drop Characteristics

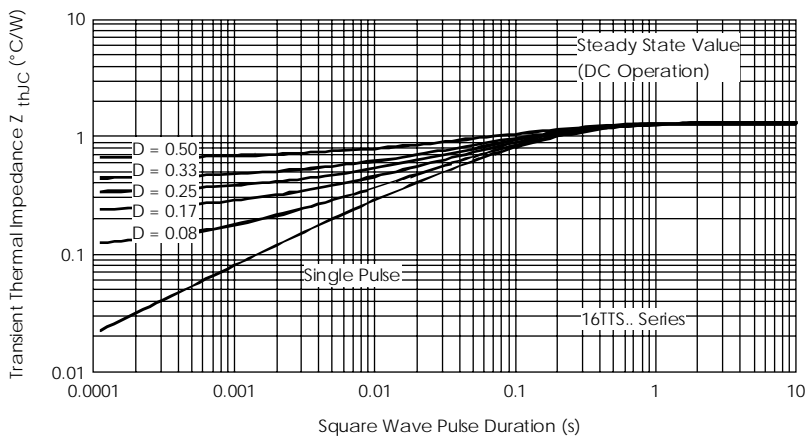


Fig. 8 - Thermal Impedance  $Z_{thJC}$  Characteristics

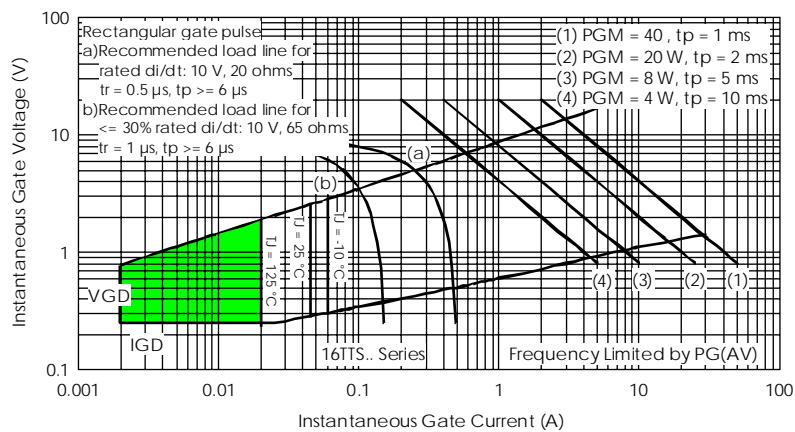
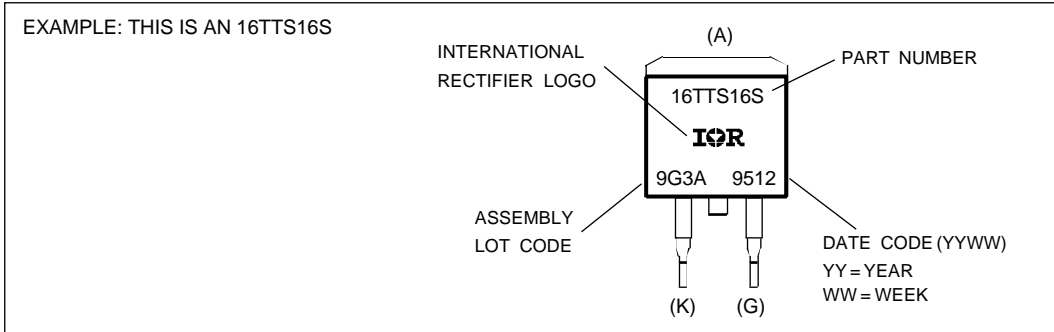
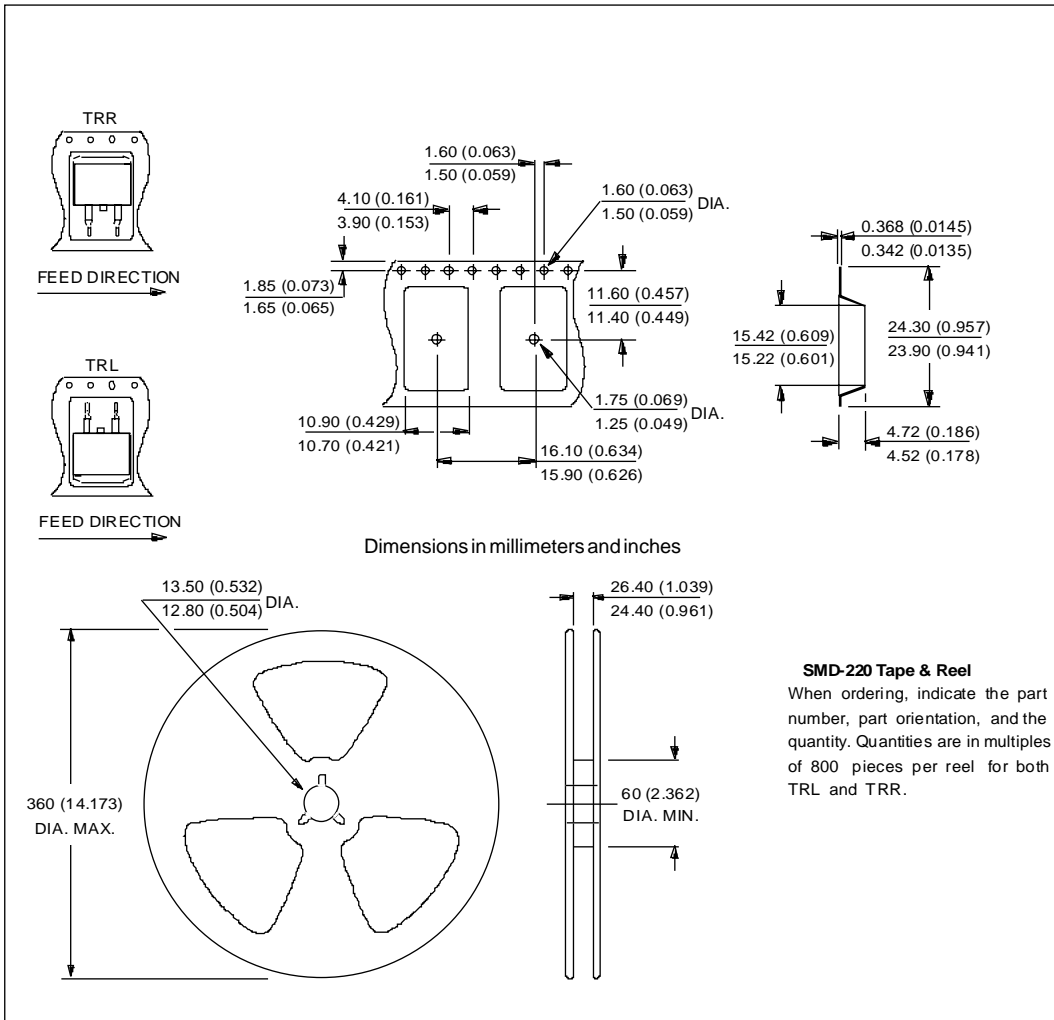


Fig. 9 - Gate Characteristics

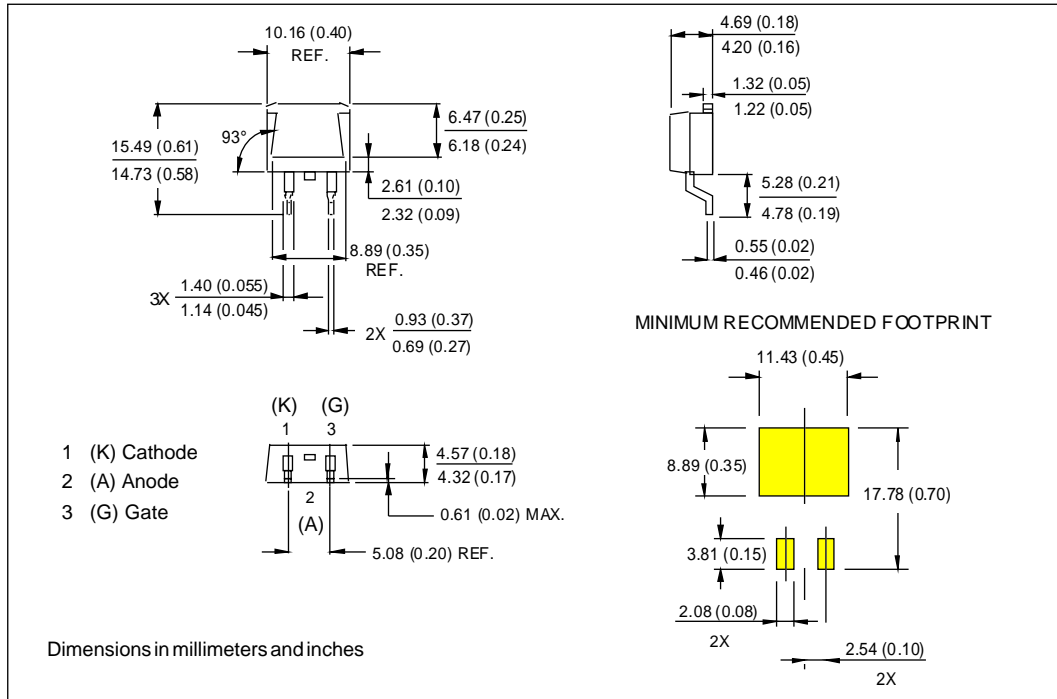
Marking Information



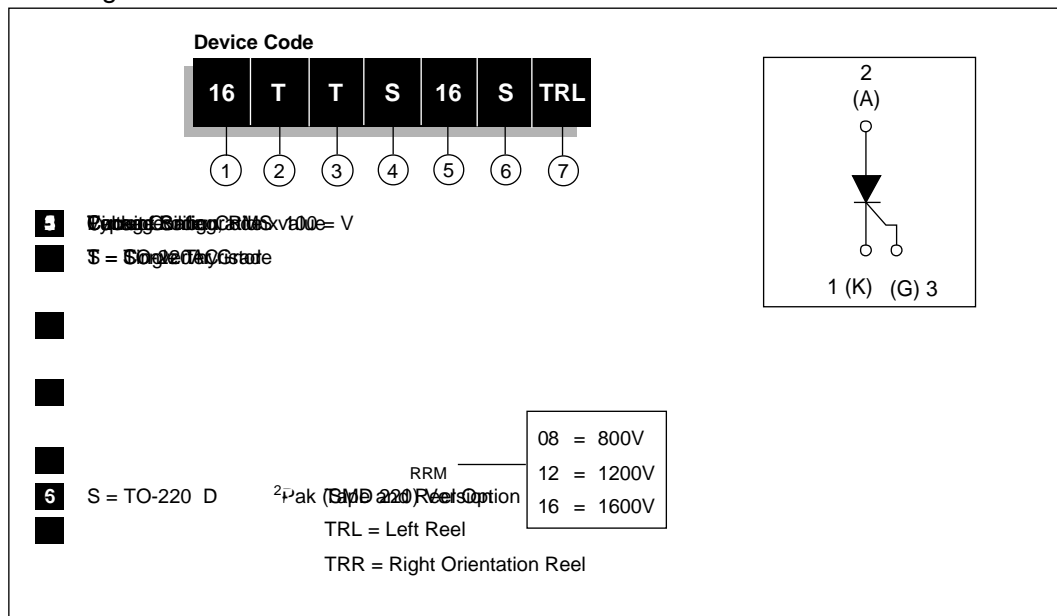
Tape & Reel Information



Outline Table



Ordering Information Table



## 16TTS.. S **SAFEIR** Series

Bulletin I2105 rev. D 12/98

International  
**IOR** Rectifier

International  
**IOR** Rectifier

**WORLD HEADQUARTERS:** 233 Kansas St., El Segundo, California 90245 U.S.A. Tel: (310) 322 3331. Fax: (310) 322 3332.  
**EUROPEAN HEADQUARTERS:** Hurst Green, Oxted, Surrey RH8 9BB, U.K. Tel: ++ 44 1883 732020. Fax: ++ 44 1883 733408.  
**IR CANADA:** 15 Lincoln Court, Brampton, Markham, Ontario L6T3Z2. Tel: (905) 453 2200. Fax: (905) 475 8801.  
**IR GERMANY:** Saalburgstrasse 157, 61350 Bad Homburg. Tel: ++ 49 6172 96590. Fax: ++ 49 6172 965933.  
**IR ITALY:** Via Liguria 49, 10071 Borgaro, Torino. Tel: ++ 39 11 4510111. Fax: ++ 39 11 4510220.  
**IR FAR EAST:** K&H Bldg., 2F, 30-4 Nishi-Ikebukuro 3-Chome, Toshima-Ku, Tokyo, Japan 171. Tel: 81 3 3983 0086.  
**IR SOUTHEAST ASIA:** 1 Kim Seng Promenade, Great World City West Tower, 13-11, Singapore 237994. Tel: ++ 65 838 4630.  
**IR TAIWAN:** 16 Fl. Suite D.207, Sec. 2, Tun Haw South Road, Taipei, 10673, Taiwan. Tel: 886 2 2377 9936.

*Fax-On-Demand: +44 1883 733420*

*Data and specifications subject to change without notice.*

Document Number: 93698

[www.vishay.com](http://www.vishay.com)

8





## Notice

The products described herein were acquired by Vishay Intertechnology, Inc., as part of its acquisition of International Rectifier's Power Control Systems (PCS) business, which closed in April 2007. Specifications of the products displayed herein are pending review by Vishay and are subject to the terms and conditions shown below.

Specifications of the products displayed herein are subject to change without notice. Vishay Intertechnology, Inc., or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document. Except as provided in Vishay's terms and conditions of sale for such products, Vishay assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of Vishay products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Vishay for any damages resulting from such improper use or sale.

International Rectifier®, IR®, the IR logo, HEXFET®, HEXSense®, HEXDIP®, DOL®, INTERO®, and POWIRTRAIN® are registered trademarks of International Rectifier Corporation in the U.S. and other countries. All other product names noted herein may be trademarks of their respective owners.